

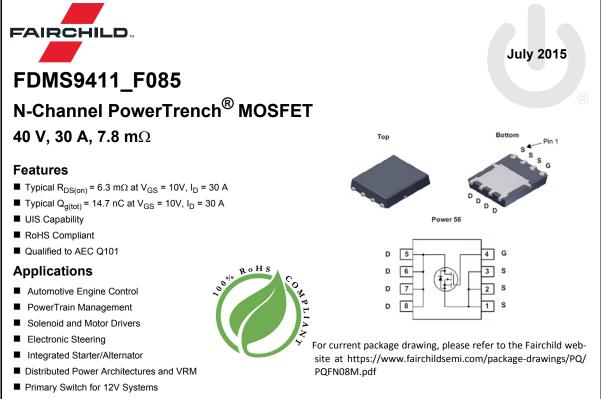
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# MOSFET Maximum Ratings T<sub>J</sub> = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-to-Source Voltage		40	V
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V
I <sub>D</sub>	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> =25°C 30		
	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure 4	Α
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	20	mJ
<b>-</b>	Power Dissipation		68.2	W
P <sub>D</sub>	Derate Above 25°C		0.45	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2.2	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W

## Notes:

1: Current is limited by bondwire configuration.

2: Starting T<sub>J</sub> = 25°C, L = 70uH, I<sub>AS</sub> = 24A, V<sub>DD</sub> = 40V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche.

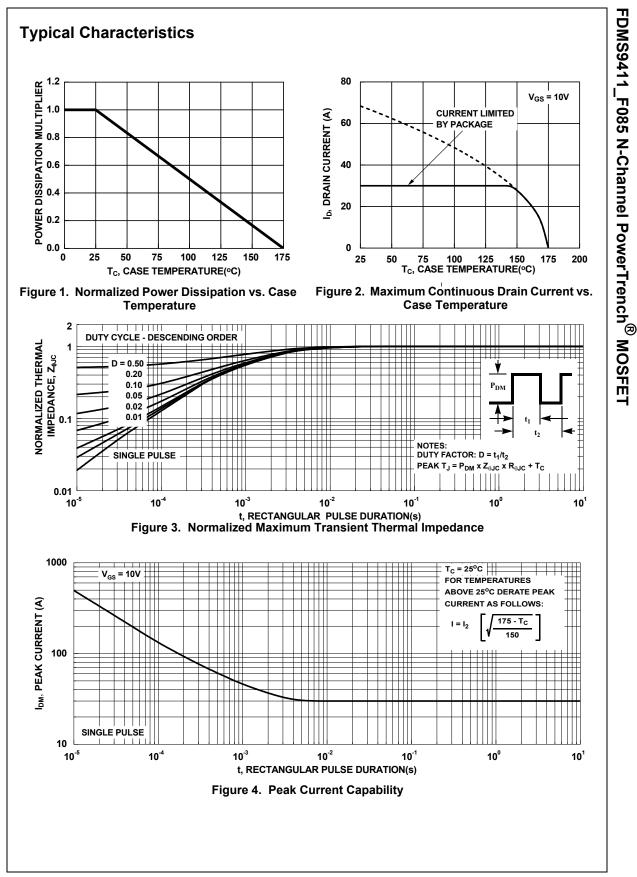
3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0JC</sub> is guaranteed by design, while R<sub>0JA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

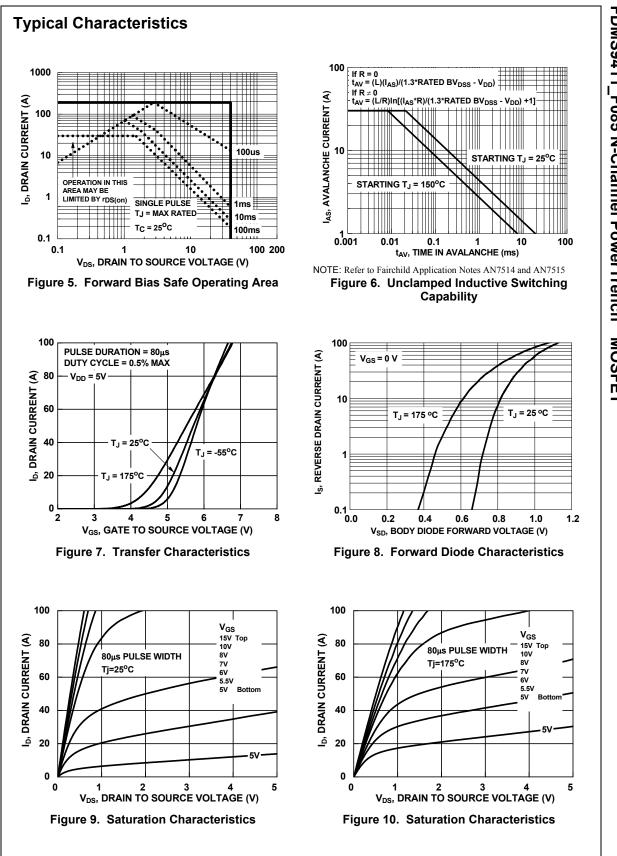
# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS9411	FDMS9411_F085	Power56	13"	12mm	3000units

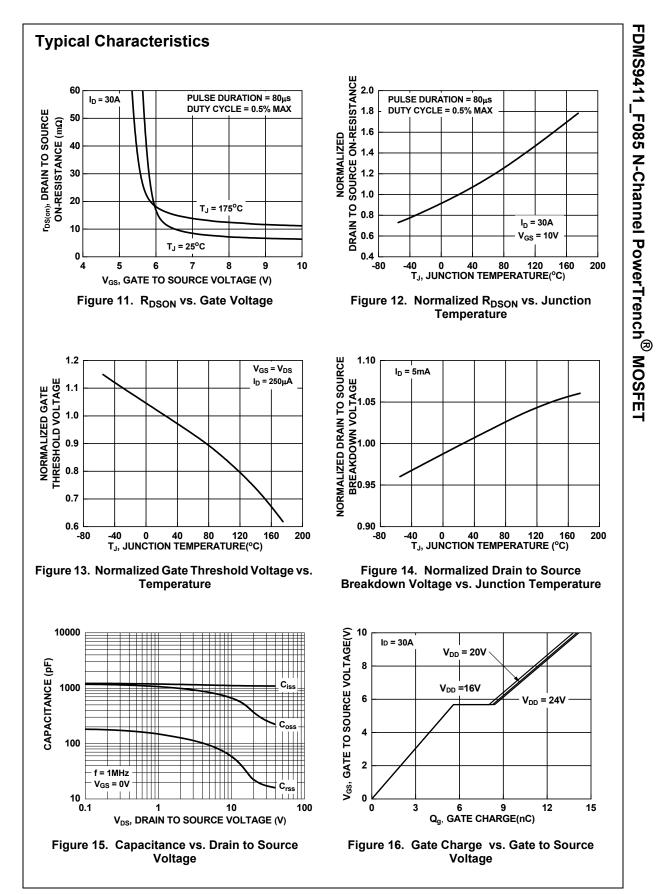
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
•	racteristics	1001 001			199.	mux.	onne
			- 0) (	40		1	N
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	$I_{\rm D} = 250 \mu A, V_{\rm GS} =$		40	-	-	V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	$V_{DS}$ =40V, $T_{J}$ =		-	-	1	μA
	Gate-to-Source Leakage Current	$V_{GS} = 0V$ $T_J = 175^{\circ}C$ (Note 4) $V_{GS} = \pm 20V$		-	-	±100	mA nA
I <sub>GSS</sub>	Gale-10-Source Leakage Current	V <sub>GS</sub> - 120V		-	-	100	ΠA
On Cha	racteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 2$	250μΑ	2.0	3.3	4.0	V
_			= 25°C	-	6.3	7.8	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 10V T <sub>J</sub> =	= 175 <sup>o</sup> C (Note 4)	-	11.2	14	mΩ
Dynami	c Characteristics						
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V, f = 1MHz f = 1MHz		-	1100	-	pF
C <sub>oss</sub>	Output Capacitance			-	370	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	23	-	pF
R <sub>g</sub>	Gate Resistance			-	2.6	-	Ω
Q <sub>g(ToT)</sub>	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V V_{DD} = 32V V_{GS} = 0 \text{ to } 2V I_D = 30A$		-	14.7	22	nC
Q <sub>q(th)</sub>	Threshold Gate Charge			-	2.0	-	nC
Q <sub>gs</sub>	Gate-to-Source Gate Charge			-	5.6	-	nC
Q <sub>gd</sub>	Gate-to-Drain "Miller" Charge			-	2.7	-	nC
Switchiı <sub>ton</sub>	ng Characteristics			-	-	16.4	ns
t <sub>d(on)</sub>	Turn-On Delay	V <sub>DD</sub> = 20V, I <sub>D</sub> = 30A,		-	9.3	-	ns
t <sub>r</sub>	Rise Time			-	3.3	-	ns
t <sub>d(off)</sub>	Turn-Off Delay	$V_{GS}$ = 10V, $R_{GEN}$	<sub>1</sub> = 6Ω	-	15.1	-	ns
t <sub>f</sub>	Fall Time			-	4.0	-	ns
t <sub>off</sub>	Turn-Off Time			-	-	24.8	ns
Drain-S	ource Diode Characteristics	II					
N (		I <sub>SD</sub> =30A, V <sub>GS</sub> = 0V		-	-	1.25	V
$V_{SD}$	Source-to-Drain Diode Voltage	I <sub>SD</sub> = 15A, V <sub>GS</sub> = 0V		-	-	1.2	V
t <sub>rr</sub>	Reverse-Recovery Time	$I_{\rm E}$ = 30A, dI <sub>SD</sub> /dt		-	36.7	48	ns
	Reverse-Recovery Charge	$V_{DD} = 32V$			20.6	27	nC

4: The maximum value is specified by design at  $T_J$  = 175°C. Product is not tested to this condition in production.





FDMS9411\_F085 N-Channel PowerTrench<sup>®</sup> MOSFET



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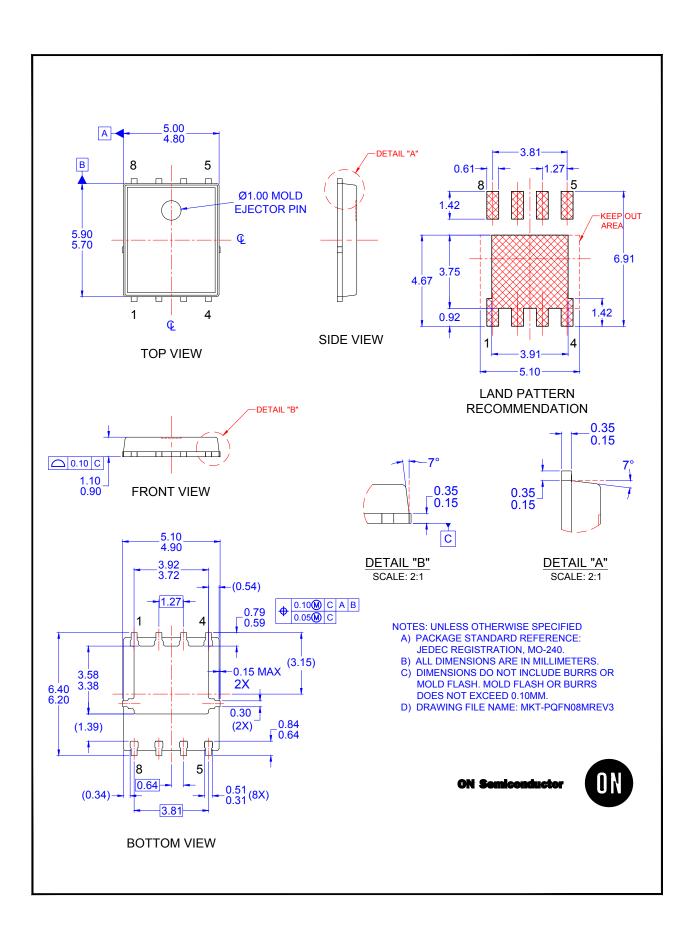
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